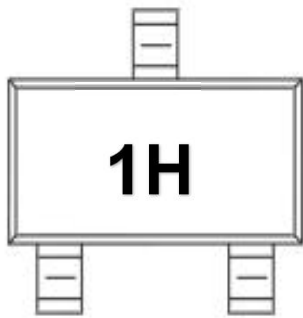
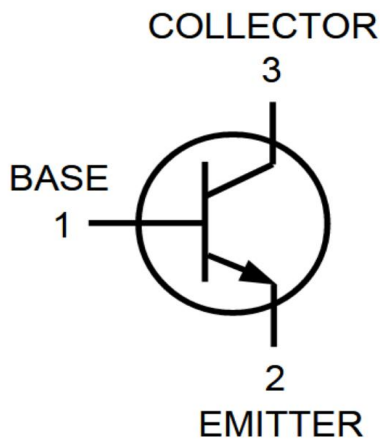
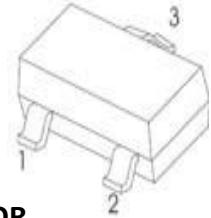


# MMBTA05

## TRANSISTOR (NPN)

**MARKING:**

**Equivalent Circuit:**

**SOT-23**

- 1.BASE
- 2.EMITTER
- 3.COLLECTOR


**FEATURES:**

※ Driver transistor

**MAXIMUM RATINGS (Ta=25°C unless otherwise noted)**

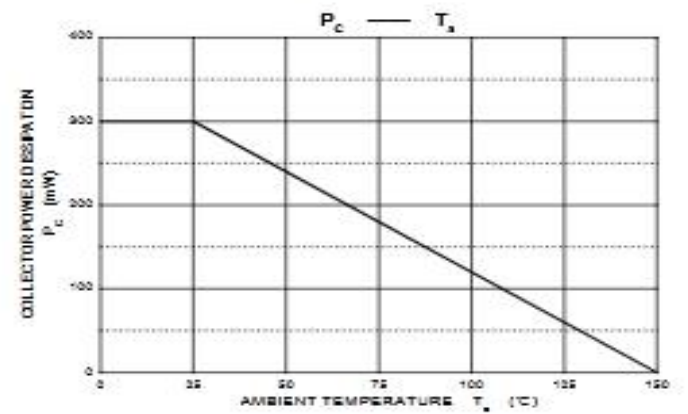
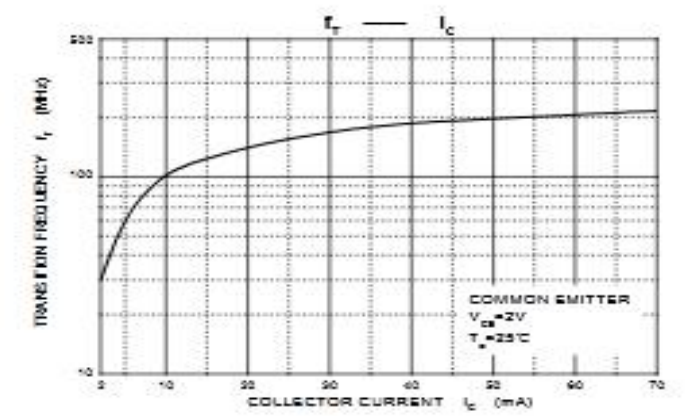
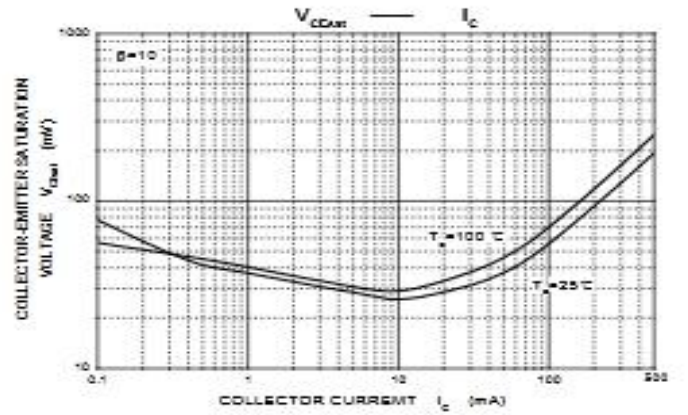
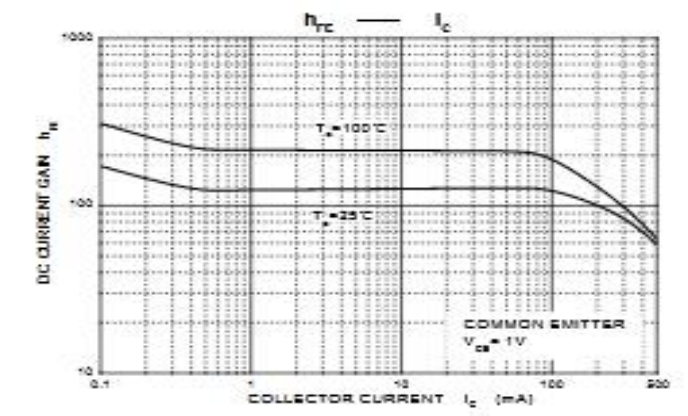
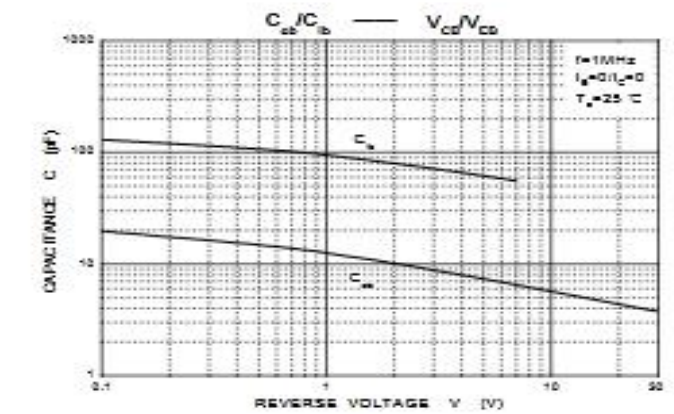
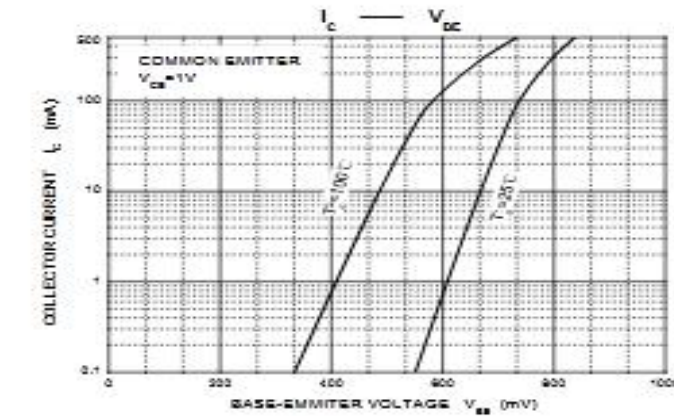
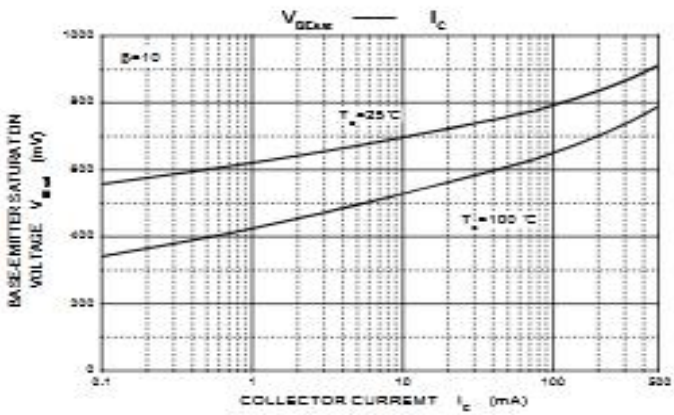
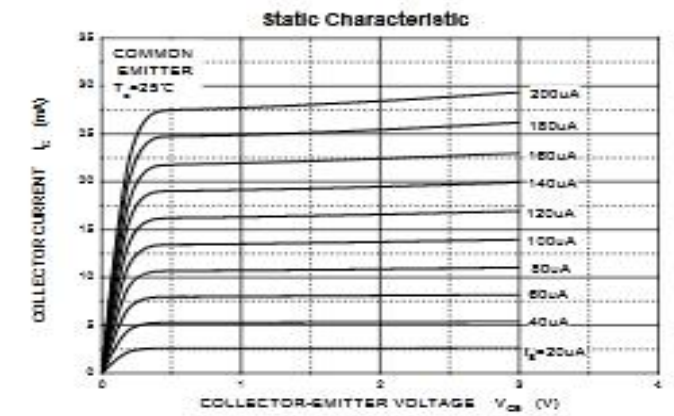
Parameter	Symbol	Value	Unit
Collector-Base Voltage	VCBO	60	V
Collector-Emitter Voltage	VCEO	60	V
Emitter-Base Voltage	VEBO	4	V
Collector Current	IC	500	mA
Collector Power Dissipation	PC	300	mW
Thermal Resistance From Junction To Ambient	ROJA	417	°C/W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55~+150	°C

**ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Collector-base breakdown voltage	<b>V(BR)CBO</b>	IC= 100μA, IE=0	60			V
Collector-emitter breakdown voltage	<b>V(BR)CEO</b>	IC= 1mA, IB=0	60			V
Emitter-base breakdown voltage	<b>V(BR)EBO</b>	IE=100μA, IC=0	4			V
Collector cut-off current	<b>ICBO</b>	VCB=60 V , IE=0			0.1	μA
Collector cut-off current	<b>ICEO</b>	VCB=60V , IE=0			0.1	μA
Emitter cut-off current	<b>IEBO</b>	VEB= 3V , IC=0			0.1	μA
DC current gain	<b>hFE</b>	VCE=1V, IC= 10mA	100		400	
	<b>hFE</b>	VCE=1V, IC= 100mA	100			
Collector-emitter saturation voltage	<b>VCE(sat)</b>	IC=100 mA, IB= 10mA			0.25	V
Base-emitter saturation voltage	<b>VBE(sat)</b>	IC=100 mA, IB= 10mA			1.2	V
Transition frequency	<b>fT</b>	VCE=2V, IC= 10mA f=100MHz	100			MHz

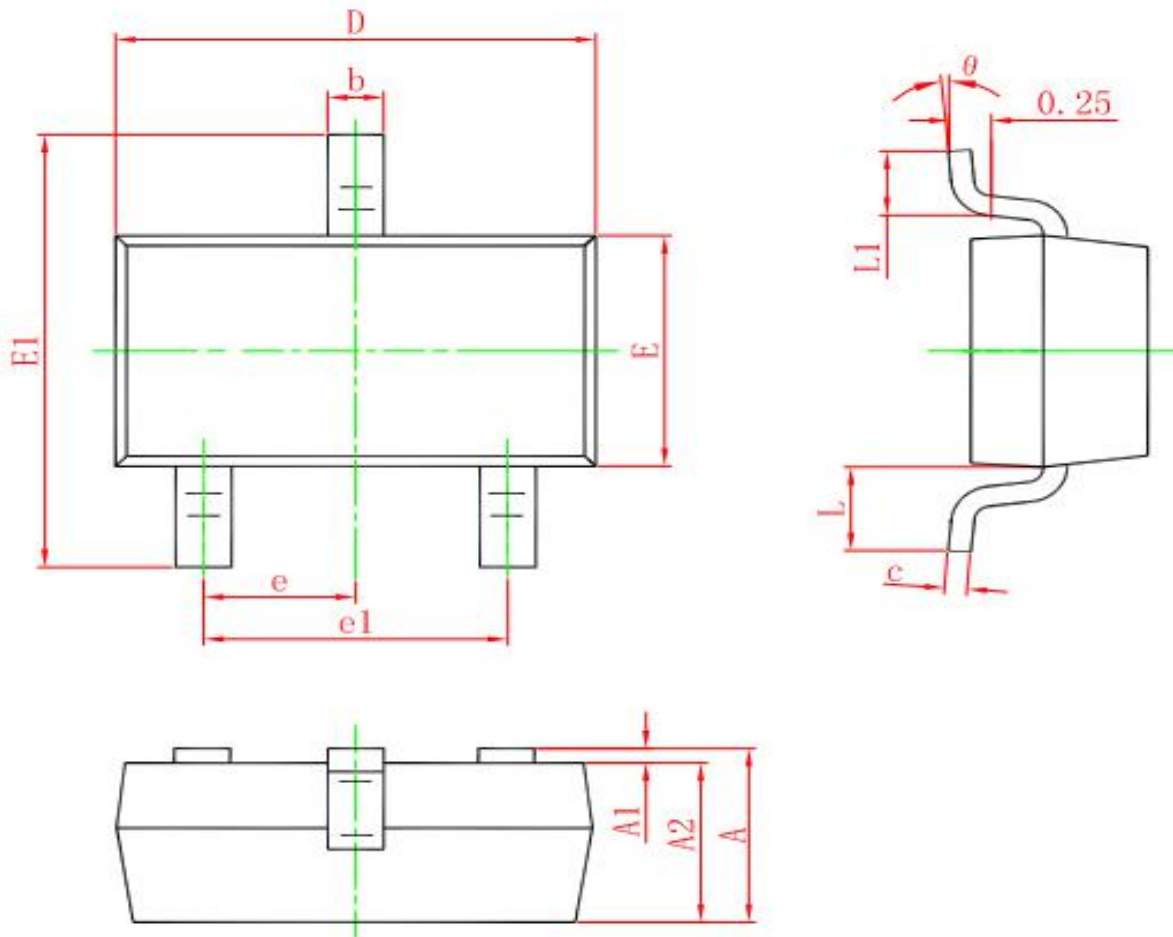
# MMBTA05

## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS



# MMBTA05

## SOT-23 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
$\theta$	0°	8°	0°	8°

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